Excellent Integrated System Limited

Stocking Distributor

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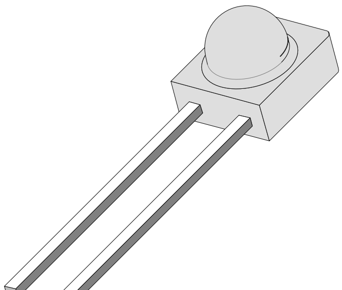
Vishay Semiconductor/Opto Division
TSSF4500

For any questions, you can email us directly:
sales@integrated-circuit.com

High Speed Infrared Emitting Diode, 890 nm, GaAlAs Double Hetero



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FEATURES

- Package type: leaded
- Package form: side view
- Dimensions (L x W x H in mm): 4.5 x 4 x 4.8
- Peak wavelength: λ_p = 890 nm
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: φ = ± 22°
- Low forward voltage
- Suitable for high pulse current operation
- High modulation bandwidth: f_c = 12 MHz
- Good spectral matching with Si photodetectors
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

RoHS COMPLIANT GREEN (5-2008)**

Note

** Please see document “Vishay Material Category Policy”: www.vishay.com/doc?99902

DESCRIPTION

TSSF4500 is an infrared, 890 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a clear, untinted plastic package.

APPLICATIONS

- Infrared high speed remote control and free air data transmission systems with high modulation frequencies or high data transmission rate requirements
- TSSF4500 is ideal for the design of transmission systems according to IrDA requirements and for carrier frequency based systems (e.g. ASK/FSK - coded, 450 kHz or 1.3 MHz)

PRODUCT SUMMARY				
COMPONENT	I_e (mW/sr)	φ (deg)	λ_p (nm)	t_r (ns)
TSSF4500	20	± 22	890	30

Note

- Test conditions see table “Basic Characteristics”

ORDERING INFORMATION			
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TSSF4500	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	Side view

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Peak forward current	t_p/T = 0.5, t_p = 100 μs	I_{FM}	200	mA
Surge forward current	t_p = 100 μs	I_{FSM}	1.5	A
Power dissipation		P_V	160	mW

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s, 2 mm from case	T_{sd}	260	°C
Thermal resistance junction/ambient	Leads not soldered	R_{thJA}	450	K/W

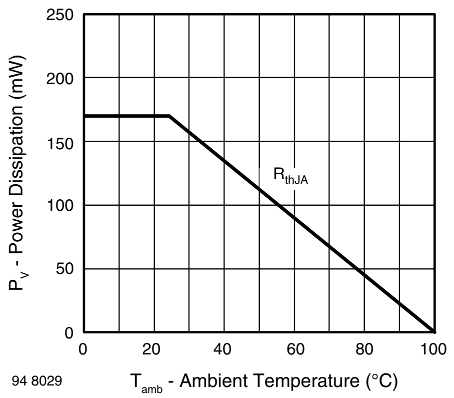


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

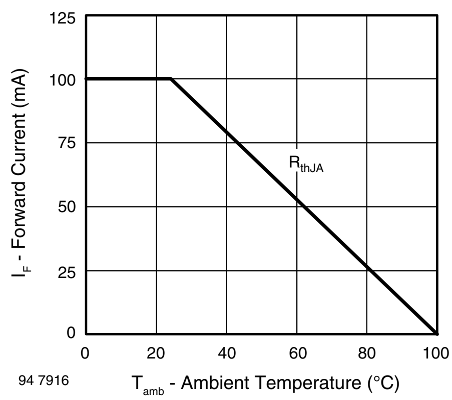


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Forward voltage	I_F = 100 mA, t_p = 20 ms	V_F		1.35	1.6	V
	I_F = 1.5 A, t_p = 100 μs	V_F		2.4		V
Temperature coefficient of V_F	I_F = 1 mA	TK_{VF}		- 1.8		mV/K
Reverse current	V_R = 5 V	I_R			10	μA
Junction capacitance	V_R = 0 V, f = 1 MHz, E = 0	C_j		160		pF
Radiant intensity	I_F = 100 mA, t_p = 20 ms	I_e	10	20	50	mW/sr
	I_F = 1 A, t_p = 100 μs	I_e		200		mW/sr
Radiant power	I_F = 100 mA, t_p = 20 ms	ϕ_e		35		mW
Temperature coefficient of ϕ_e	I_F = 100 mA	$TK\phi_e$		- 0.7		%/K
Angle of half intensity		φ		± 22		deg
Peak wavelength	I_F = 100 mA	λ_p		890		nm
Spectral bandwidth	I_F = 100 mA	$\Delta\lambda$		40		nm
Temperature coefficient of λ_p	I_F = 100 mA	$TK\lambda_p$		0.2		nm/K
Rise time	I_F = 100 mA	t_r		30		ns
Fall time	I_F = 100 mA	t_f		30		ns
Cut-off frequency	I_{DC} = 70 mA, I_{AC} = 30 mA pp	f_c		12		MHz
Virtual source diameter		d		2.1		mm

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

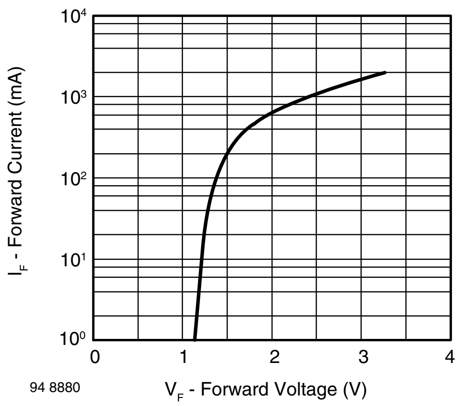


Fig. 3 - Forward Current vs. Forward Voltage

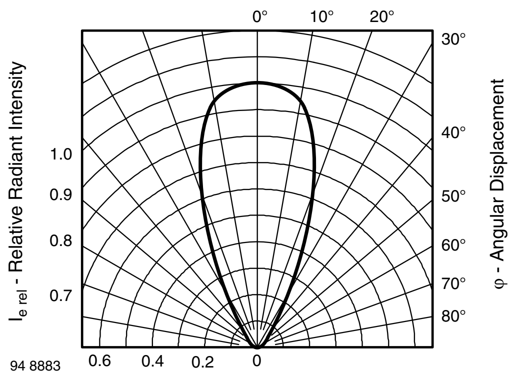


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

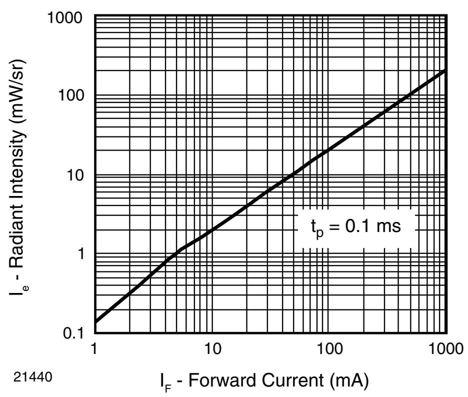


Fig. 4 - Radiant Intensity vs. Forward Current

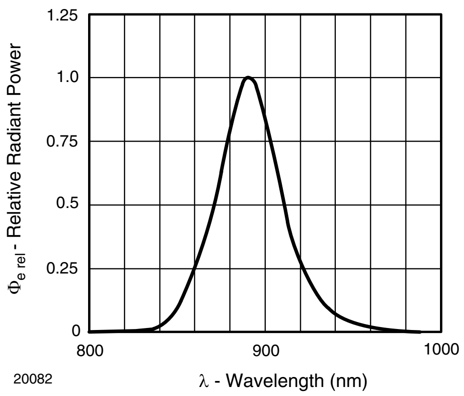
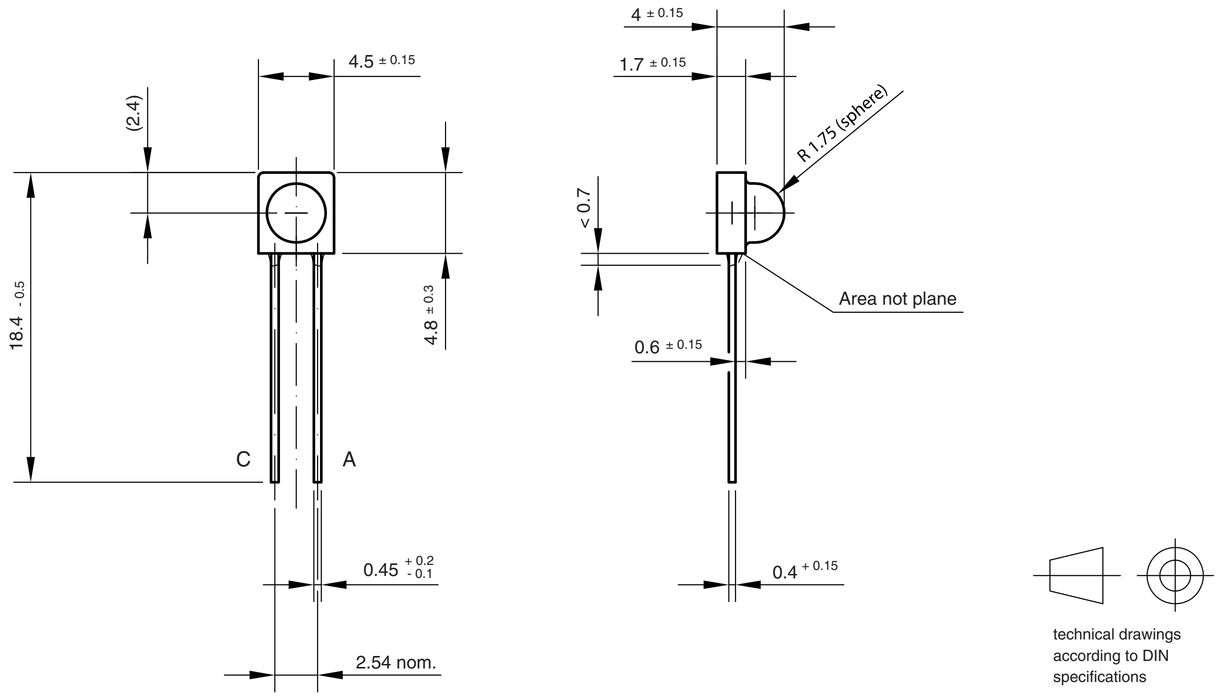


Fig. 5 - Relative Radiant Power vs. Wavelength

PACKAGE DIMENSIONS in millimeters



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Issue:1; 01.07.96
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